# **BC817**



### BC817 SOT-23 Plastic-Encapsulate Transistors (NPN)

#### **General description**

SOT-23 Plastic-Encapsulate Transistors (NPN)

#### FEATURES

- Complementary to BC807
- Power Dissipation of 300mW
- High Stability and High Reliability
- SOT-23 Small Outline Plastic Package
- Epoxy UL: 94V-0
- Mounting Position: Any



#### **DEVICE MARKING CODE:**

#### Maximum Ratings & Thermal Characteristics (Ratings at 25°C ambient temperature unless otherwise specified.)

Parameters	Symbols	Value	Unit
Collector-Base Voltage	Vсво	50	V
Collector-Emitter Voltage	VCEO	45	V
Emitter -Base Voltage	Vebo	5	V
Collector Current-Continuous	lc	500	mA
Collector Power Dissipation	Pc	300	mW
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-55-+150	°C
Thermal resistance From junction to ambient	Reja	417	°C/W

### Electrical Characteristics (Ratings at 25°C ambient temperature unless otherwise specified).

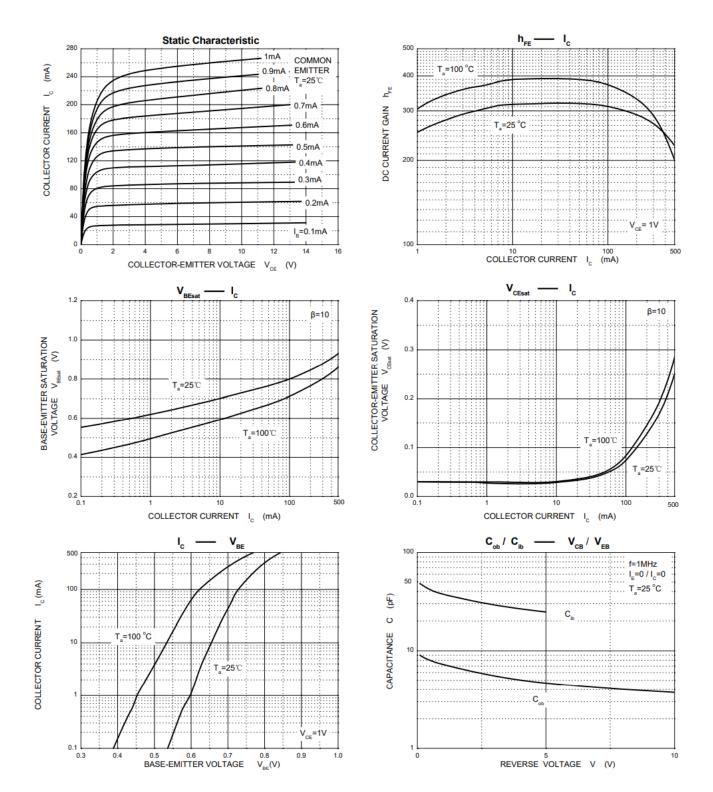
Parameter	Symbolo	Test Condition	Limits		l lmit
Parameter	Symbols	lest condition	Min	Max	Unit
Collector-base breakdown voltage	V(BR)CBO	IC=10uA, IE=0	50		V
Collector-emitter breakdown voltage	V(BR)CEO	IC=10mA, IB=0	45		V
Emitter-base breakdown voltage	V(BR)EBO	IE=1uA, IC=0	5		V
Collector cut-off current	Ісво	VCB=45V, IE=0		100	nA
Emitter cut-off current	IEBO	VEB=4V, IC=0		100	nA
DC current gain	hFE(1)	VCE=1V, IC=100mA	100	600	
	hFE(2)	VCE=1V, IC=500mA	40		
Collector-emitter saturation voltage	VCE(sat)	IC=500mA, IB=50mA		0.70	V
Base -emitter saturation voltage	VBE(sat)	IC=500mA, IB=50mA		1.20	V
Base-emitter voltage	VBE	VCE=1V, IC=500mA		1.20	
Collecter capactiance	Cob	VCB=10V, f=1MHz	10(	Тур)	
Transition frequency	fT	VCE=5V, IC=10mA,f=100MHz	100		MHz

## **CLASSIFICATION OF hFE(1)**

RANK	BC817-16	BC817-25	BC817-40	
RANGE	100-250	160-400	250-600	
Marking	6A	6B	6C	

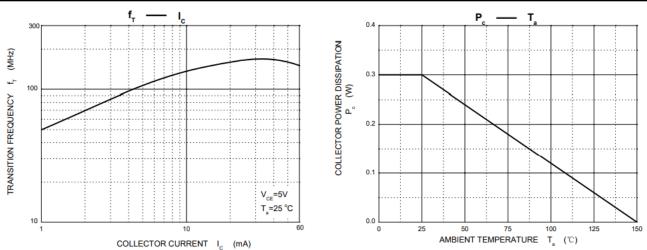


# BC817 RATING AND CHARACTERISTIC CURVES

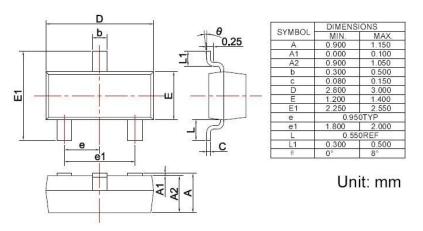


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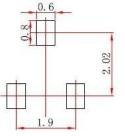




## SOT-23 PACKAGE OUTLINE Plastic surface mounted package



Precautions: PCB Design Recommended land dimensions for SOT-23 diode. Electrode patterns for PCBs



Note:

1.Controlling dimension: In millimeters.

2.General tolerance:±0.05mm. 3.The pad layout is for reference purposes only.



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